NSN 5961-01-408-6782

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-408-6782 **Inclosure Material:** Plastic **Overall Length:** 0.210 inches **Overall Height:** 0.165 inches **Overall Width:** 0.205 inches **End Application:** 6625-01-363-6212 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.7 limiting voltage **Current Rating Per Characteristic:** 20.00 milliamperes source cutoff current preset and 50.00 milliamperes forward current, average outside diameter **Power Rating Per Characteristic:** 360.0 milliwatts small-signal input power, common-collector absolute **Capacitance Rating In Picofarads:** 2.0 **Maximum Operating Tempurature Per Measurement Point:** 135.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No